

644CNQ045

Technical Data Data Sheet N1241, Rev. B **Green Products**

644CNQ045 SCHOTTKY RECTIFIER

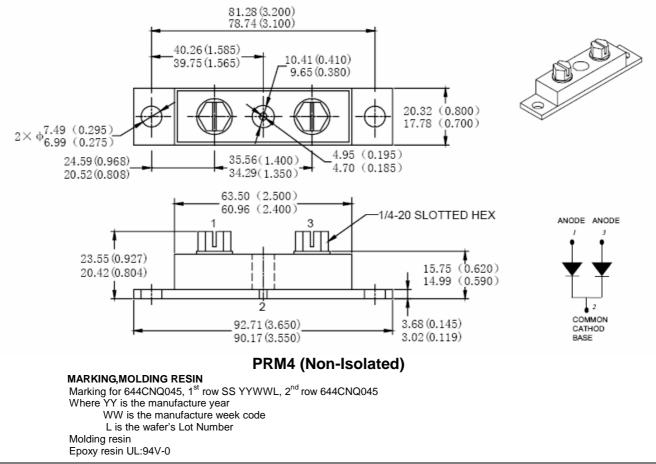
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection
 Converters
 UPS System
 Welding

Features:

- 125 ℃ T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Mechanical Dimensions: In mm/ Inches



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SANGDEST MICROELECTRONICS

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Characteristics	Symbol	Condition	Max. 45		Units V
Peak Inverse Voltage	V _{RWM}	-			
Max. Average Forward	I _{F(AV)}	50% duty cycle @T _C =80℃,	300	per leg	Α
Current		rectangular wave form	600	per device	
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	4560		A
Non-Repetitive Avalanche Energy(peg leg)	E _{AS}	T _J =25℃,I _{AS} =40A,L=0.34mH	270		mJ
Repetitive Avalanche Current(peg leg)	I _{AR}	Current decaying linearly to zero in 1 μ sec Frequency limited by T _J max. V _A =1.5× V _R typical		40	A

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V _{F1}	@ 300A, Pulse, T _J = 25 °C	0.65	V
(per leg) *	V _{F2}	@ 300A, Pulse, T _J = 125 °C	0.60	V
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = rated V_R T_J = 25 °C$	20	mA
	I _{R2}	$@V_R = rated V_R T_J = 125 \ ^{\circ}C$	2400	mA
Max. Junction Capacitance (per leg)	C _T	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	10300	pF
Typical Series Inductance (per leg)	L _S	Measured lead to lead 5 mm from package body	5.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs
Insulation Voltage	V _{RMS}	-	1000	V

* Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specifi	Units			
Max. Junction Temperature	ΤJ	-	-55 to	°C			
Max. Storage Temperature	T _{stg}	-	-55 to	°C			
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.20		°C/W		
Maximum Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.10		°C/W		
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.1	°C/W			
Mounting Torque	Тм	-	Mounting Torque Terminal Torque	24(min) 35(max) 35(min) 46(max)	Kg-cm		
Approximate Weight	wt	-	79	g			
Case Style	PRM4 Non-Isolated						



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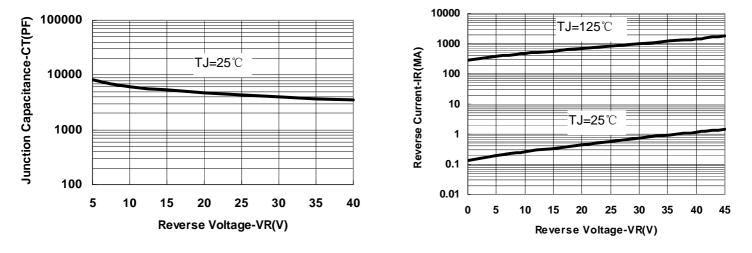
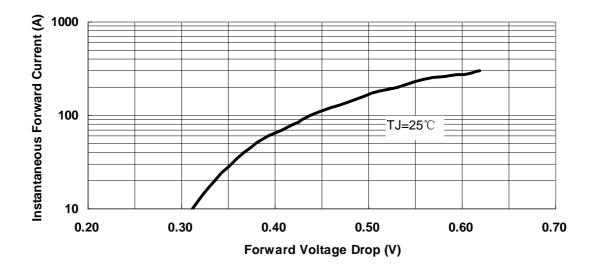




Fig.2-Typical Reverse Characteristics







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